TOSHIBA Bipolar Linear IC Silicon Monolithic

TA2131FNG

Low Current Consumption Headphone Amplifier for Portable MD Player (With Bass Boost Function)

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The TA2131FNG is a low current consumption headphone amplifier developed for portable digital audio. It is particularly well suited to portable MD players that are driven by a single dry cell. It also features a built-in bass boost function with AGC, and is capable of bass amplification of DAC output and analog signals such as tuner.

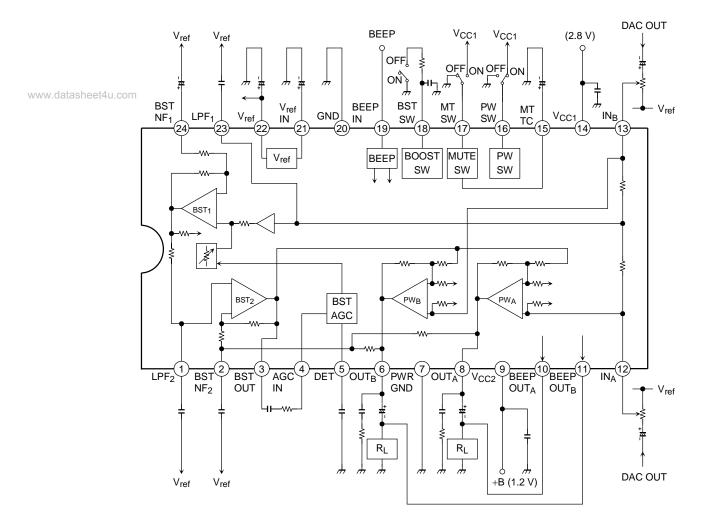
Features

- Low current consumption: ICCQ (VCC1) = 0.55 mA (typ.) ICCQ (VCC2) = 0.20 mA (typ.)
- Output power: P₀ = 8 mW (typ.) (V_{CC1} = 2.8 V, V_{CC2} = 1.2 V, f = 1 kHz, THD = 10%, R_L = 16 \Omega)
- Low noise: $V_{no} = -102 dBV$ (typ.)
- Built-in low-pass boost (with AGC)
- I/O pin for beep sound
- Outstanding ripple rejection ratio
- Built-in power mute
- Built-in power ON/OFF switch
- Operating supply voltage range (Ta = 25°C): V_{CC1} = 1.8~4.5 V V_{CC2} = 0.9~4.5 V



Weight: 0.14 g (typ.)

Block Diagram



Terminal Explanation (Terminal voltage: Typical terminal voltage at no signal with test circuit, $V_{CC1} = 2.8 \text{ V}$, $V_{CC2} = 1.2 \text{ V}$, $Ta = 25 ^{\circ}\text{C}$)

	Te	erminal No.	Terminal Explanation	Internal Circuit	Terminal Voltage (V)
www.datasheet4i	ı.com 1	LPF ₂	BST amplifier 1 output (filter terminal)	PW _A 12 20 kΩ ADD AGC BST ₁ G BST ₂ R AMP	0.61
	23	LPF ₁	ADD amplifier output (filter terminal)	PW _B 30 kΩ	0.61
	24	BST NF ₁	BST amplifier 1 NF	Vref Vref	0.61
	2	BST NF ₂	BST amplifier 2 NF terminal (low-pass compensation condenser connection terminal)	CS W PWA	0.61
	3	BST OUT	BST amplifier 2 output terminal	20 KΩ 20 KΩ 10 KΩ 10 KΩ 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8	
	6	OUTB	Power amplifier	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	0.61
	8	OUT _A	output	10 kΩ 15 kΩ	
	12	IN _A	Power amplifier		0.61
	13	IN _B	input	PW _B	0.01

		Terminal Explanation	Internal Circuit	Terminal Voltage (V)	
www.datasheet4i	4 AGC IN		Signal input level to BST amplifier is varied according to the input level to the boost AGC input terminal. Input impedance: $15~\mathrm{k}\Omega$ (typ.)	14 Vref 10 kΩ	0.61
	5	DET	Smoothing of boost AGC level detection	5.1 kg	_
	7	PWR GND	GND of power amplifier output stage	_	0
	9	V _{CC2}	V _{CC} (+B) at power amplifier output stage		1.2
		BEEP OUT _A	Beep sound output	19 10 kΩ	_
		BEEP OUT _B	terminai		
	19	BEEP IN	Beep sound input terminal Receives beep sound signals from microcomputer.		0
	14	V _{CC1}	Main V _{CC}	1	2.8
	15	МТ ТС	Mute smoothing Power mute switch Reduces the shock noise during switching	15 W (15 K)	1.2

	Terminal No. Terminal Explanation		Terminal Explanation	Internal Circuit	
www.datasheet4i	ı.com 16	PW SW	Power ON/OFF switch "H" level: IC operation "L" level: IC OFF Refer to function explanation 5	VCC1 47 kΩ (6) W	_
	17	MT SW	Mute switch "L" level: mute reset "H" level: mute ON Refer to function explanation 5	V _{CC1} 14 47 kΩ 17 m	_
	18	BST SW	Bass boost ON/OFF switch "H" level/OPEN: BST ON "L" level: BST OFF Refer to function explanation 5	14 20 kΩ 18 20 kΩ	
	20	GND	GND of input stage in power amplifier	_	0
	21 V _{ref} IN Reference voltage circuit filter terminal		Reference voltage circuit filter terminal	14 W 4 W 7 W 7 W 7 W 7 W 7 W 7 W 7 W 7	0.61
	22	V _{ref}	Reference voltage circuit	10 kΩ (22)	0.61

Function Explanation

1. Bass Boost Function

1-1 Description of Operation

TA2131FNG has a bass boost function for bass sound reproduction built-in to the power amplifier. With the bass boost function, at medium levels and lower, channel A and channel B are added for the low frequency component, and output to BST amplifier 2 (BST₂) in negative phase. That signal is inverted and added before being subjected to bass boost. If the signal of the low-frequency component reaches a high level, the boost gain is controlled to main a low distortion (see Fig.1).

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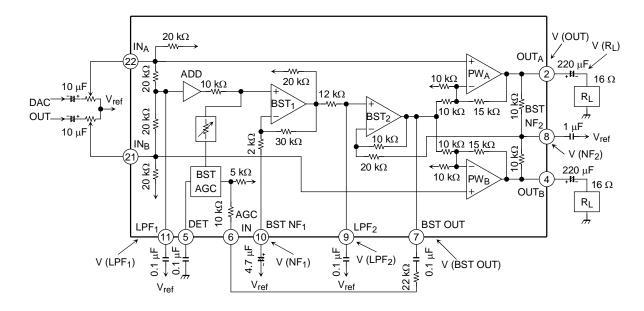


Figure 1 System Diagram of Bass Boost

1-2 AGC Circuit

The AGC circuit of the bass boost function detects with "AGC DET" the voltage component created by "BST2," and as the input level increases, the variable impedance circuit is changed, and the bass boost signal is controlled so that it is not assigned to BST amplifier 1. In this way, the bass signal to "BST2" input is shut-off, and that boost gain is controlled.

1-3 Bass Boost System

As shown in Fig.1, the flow of the bass boost signal is that the signal received from power amplifier input goes through LPF₁, ADD amplifier, ATT (variable impedance circuit), BPF₁ (BST amplifier 1) and LPF₂, and the negative phase signal to the power amplifier input signal is output from BST amplifier 2. The reason why it becomes the negative phase of the BST amplifier 2 signal is that the phase is inverted by 180° in the audible bandwidth by the secondary characteristics of LPF₁ and LPF₂ in Fig.1.

Ultimately the main signal and the bass boost signal formed before BST₂ are added. Fig.2 shows the frequency characteristics to each terminal.

0 V(RL) V(BST OUT) V(NF2) V(NF1) V(SST OUT) V(LPF1) V(LPF1) V(LPF1) To least 100 k to least 100

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Figure 2 During Bass Boost (Frequency Characteristics to Each Terminal)

2. Low-Pass Compensation

2-1. Function

In C-couple type power amplifiers, it is necessary to give the output condenser C a large capacity to flatten out the frequency characteristics to the low frequency band (this is because the loss in the low frequency bandwidth becomes larger due to the effect of the high-pass filter comprising C and R_L). Particularly when the headphone load is approximately 16 Ω and an attempt is being made to achieve frequency characteristics of ±3 dB at 20 Hz, a large capacity condenser of C = 470 μ F is required. Bearing this situation in mind, a low-pass compensation function was built in to the TA2131FNG, and while reducing the capacity of the output coupling condenser, almost flat (±3 dB) frequency characteristics in all audible bandwidths (20 Hz to 20 kHz) have been achieved. Fig.3 shows the low-pass system diagram, and Fig.4 shows the frequency characteristics at each point. In Fig.4, (a) represents the status lost by the low-pass as a result of the high-pass filter comprising the headphone load (R_L = 16 Ω) and the output coupling condenser (220 μ F) in the C-coupling system.

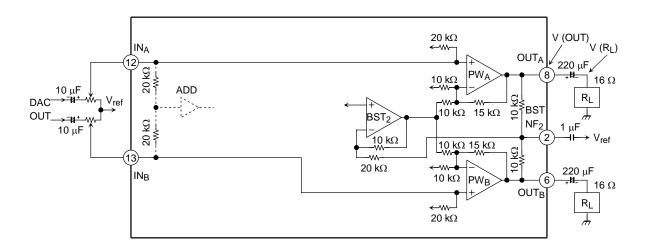


Figure 3 Low-Pass Compensation System Diagram

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Figure 4 Power Amplifier Frequency Characteristics

<Principle of Low-Pass Compensation>

The low-pass component alone is extracted from the composite signal of PWA/PWB output, and that frequency signal is fed back to PWA/PWB once more via the inversion amplifier, thereby making it possible to increase the gain only of the low-pass component. The frequency characteristics of the power amplifier output V (OUT) in this state are shown in Fig.4 (b). In practice they are the frequency characteristics (c) viewed from load terminal V (RL), and the low-pass is compensated relative to the state in (a).

2-2. Low-Pass Compensation Condenser and Crosstalk

In this low-pass compensation condenser circuit, processing is carried out using the composite signal of power amplifier output, so this affects crosstalk, according to the amount of compensation. f characteristics and crosstalk generated by the capacity of the condenser for compensation (2-pin) are shown below.

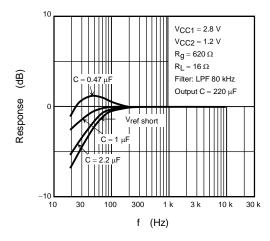


Figure 5 Condenser and f Characteristics for Low-Pass Compensation

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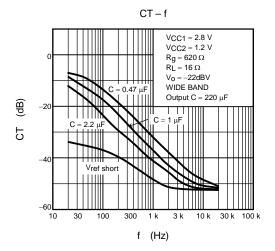
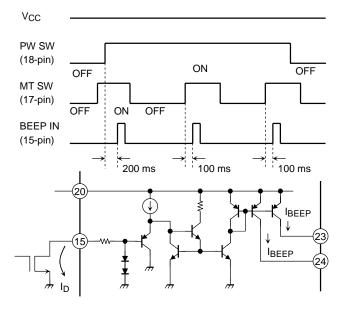


Figure 6 Low-Pass Compensation Condenser and Crosstalk

3. Beep

Beep sound signals from microcomputer can be received by the beep input terminal (19-pin). The PWA and PWB of the power amplifier during power mute are turned OFF, and the beep signal input from BEEP-IN (19-pin) is output from the BEEP-OUT terminal (10/11-pin) as fixed current, after passing through the converter and current amplification stage. Connecting this terminal to the headphone load outputs the beep sound.

If the beep sound is not input, fix the BEEP-IN (19-pin) terminal to GND level.

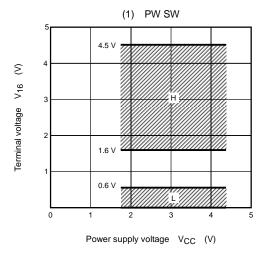


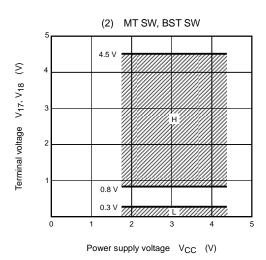
4. Power Switch

As long as the power switch is not connected to "H" level, the IC does not operate. If it malfunctions due to external noise, however, it is recommended to connect a pull-down resistor externally (the power switch is set to be highly sensitive).

5. Threshold Voltages of Switches

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	PW SW (V ₁₆)		
"H" level	IC operation		
"L" level	IC OFF		

	MT SW (V ₁₇)
"H" level	Mute ON
"L" level	Mute reset

	BST SW (V ₁₈)		
"H" level/OPEN	BST ON		
"L" level	BST OFF		

6. These capacitors which prevent oscillation of the power amplifier, and are between the V_{ref} and V_{CC} -GND must have a small temperature coefficient and outstanding frequency characteristics.

Absolute Maximum Ratings

	Characteristic	Symbol	Rating	Unit
-	Supply voltage	V _{CC}	4.5	V
(Output current	I _{o (peak)}	100	mA
Ī	Power dissipation	P _D (Note)	500	mW
+ 11	Operating temperature	T _{opr}	-25~75	°C
;	Storage temperature	T _{stg}	-55~150	°C

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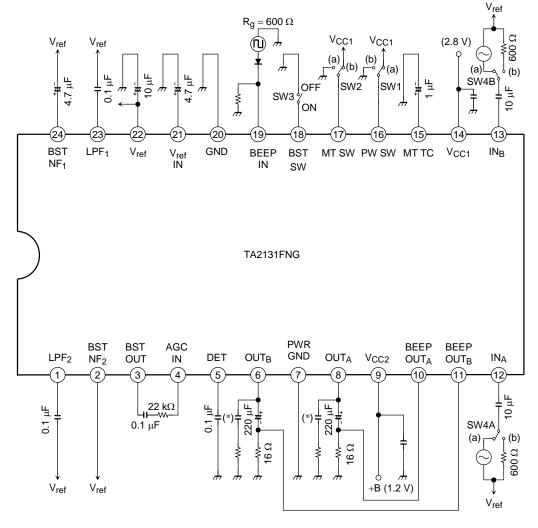
Note: Derated above $Ta = 25^{\circ}C$ in the proportion of 4 mW/°C.

Electrical Characteristics (Unless specified otherwise, V_{CC1} = 2.8 V, V_{CC2} = 1.2 V, R_g = 600 Ω , R_L = 16 Ω , f = 1 kHz, Ta = 25°C)

Characteristic		Symbol	Test condition	Min	Тур.	Max	Unit	
_		I _{CC1}	IC OFF (V _{CC1}), SW1: b, SW2: b	_	0.1	5	μА	
		I _{CC2}	IC OFF (V _{CC2}), SW1: b, SW2: b	_	0.1	5	μΑ	
Ouid	escent supply current	I _{CC3}	MUTE ON (V _{CC1}), SW1: a, SW2: b	_	0.35	0.50	mA	
Quit	escent supply current	I _{CC4}	MUTE ON (V _{CC2}), SW1: a, SW2: b	_	5	10	μА	
		I _{CC5}	No signal (V _{CC1}), SW1: a, SW2: a	_	0.55	0.75	mA	
		I _{CC6}	No signal (V _{CC2}), SW1: a, SW2: a	_	0.20	0.40		
Pow	ver supply current during	I _{CC7}	$P_0 = 0.5 \text{ mW} + 0.5 \text{ mW} \text{ output (V}_{CC1})$	_	0.6	_		
driv	е	I _{CC8}	$P_0 = 0.5 \text{ mW} + 0.5 \text{ mW} \text{ output (V}_{CC2})$	_	5.3	_		
	Gain	G _V	$V_0 = -22 dBV$	10	12	14	dB	
	Channel balance	СВ	$V_0 = -22 dBV$	-1.5	0	1.5	uБ	
	Output power	P _{omax}	THD = 10%	5	8	_	mW	
	Total harmonic distortion	THD	P ₀ = 1 mW	_	0.1	0.3	%	
tion	Output noise voltage	V _{no}	$R_g = 600 \Omega$, Filter: IHF-A, SW4: b	_	-102	-96	dBV	
Sec	Crosstalk	СТ	$V_0 = -22 dBV$	-42	-48	_		
Power Section	Ripple rejection ratio	RR1	$f_r = 100 \text{ Hz}, V_r = -20 \text{dBV}$ inflow to V_{CC2}	-71	-77	_	dB	
	Rippie rejection ratio	RR2	$f_r = 100 \text{ Hz}, V_r = -20 \text{dBV}$ inflow to V_{CC1}	-54	-64	_	αБ	
	Mute attenuation	ATT	$V_0 = -12 dBV$, SW2: $a \rightarrow b$	-90	-100	_		
	Beep sound output voltage	VBEEP	V Beep IN = 2 V _{p-o} , SW2: b	-53	-48	-43	dBV	
		BST1	$V_0 = -20$ dBV, $f = 100$ Hz, SW3: ON \rightarrow OPEN	1	4	7		
Воо	st gain	BST2	$V_0 = -30$ dBV, $f = 100$ Hz, SW3: ON \rightarrow OPEN	10	13	16	dB	
		BST3	$V_0 = -50$ dBV, $f = 100$ Hz, SW3: ON \rightarrow OPEN	13.5	16.5	19.5		

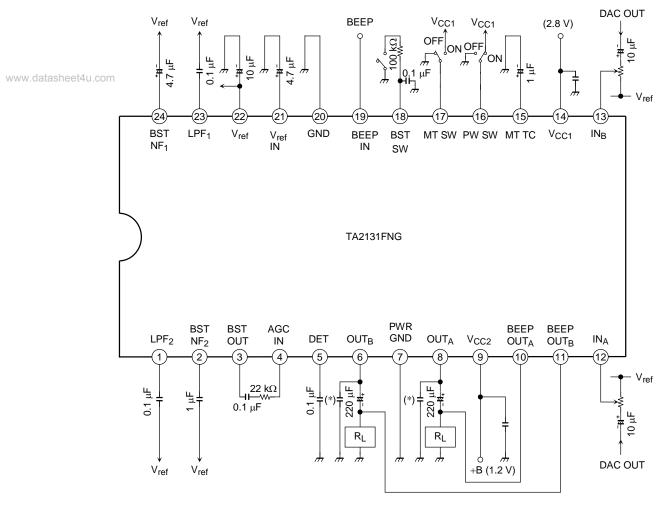
Test Circuit

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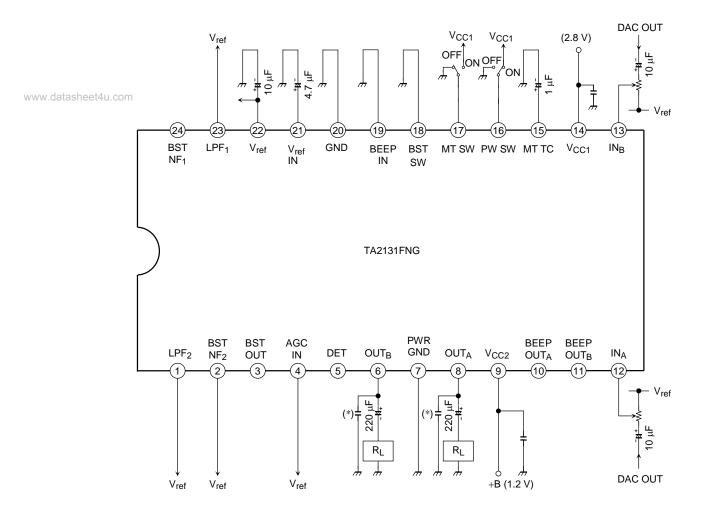
(*) $0.22~\mu\text{F} + 10~\Omega$ Monolithic ceramic capacitor

Application Circuit 1



(*) 0.22 μ F + 10 Ω Monolithic ceramic capacitor

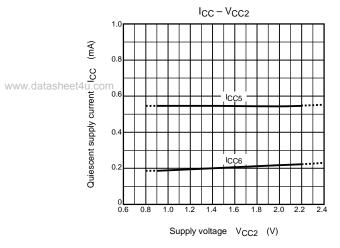
Application Circuit 2 (Low-Pass Compensation/Bass Boost Function/Beep Not Used)

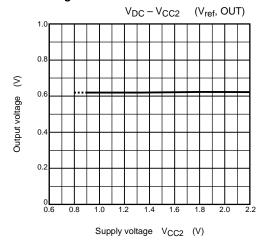


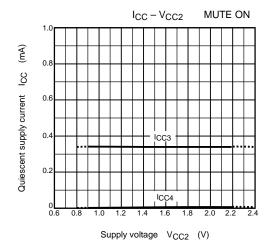
(*) 0.22 μ F + 10 Ω Monolithic ceramic capacitor

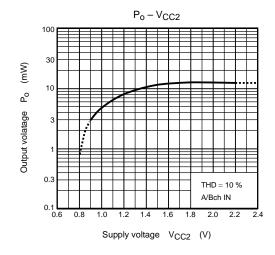
Characteristics

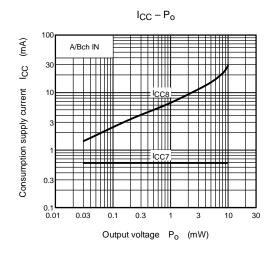
(Unless otherwise specified V_{CC1} = 2.8 V, V_{CC2} = 1.2 V, R_g = 600 Ω , f = 1 kHz, Ta = 25°C)

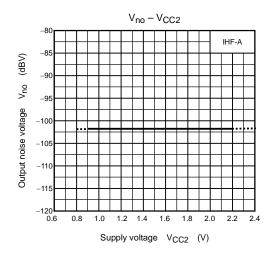


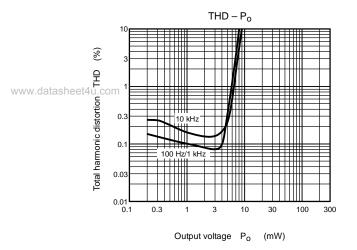


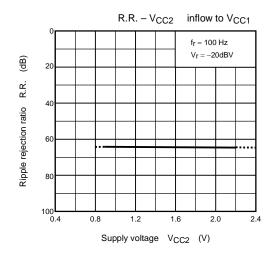


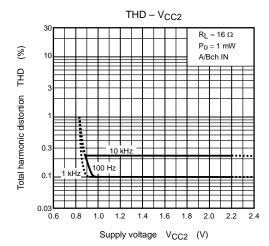


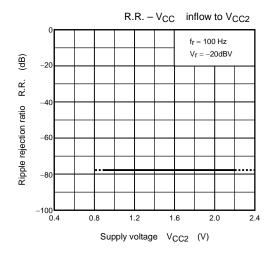


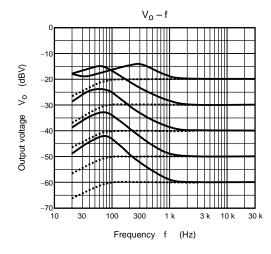


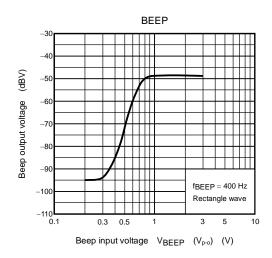


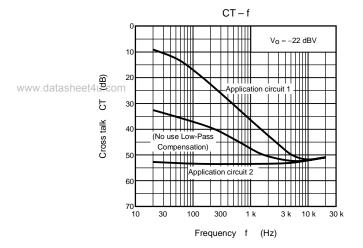


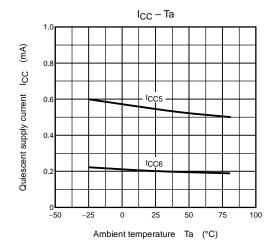


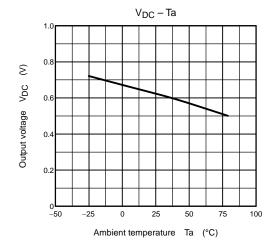




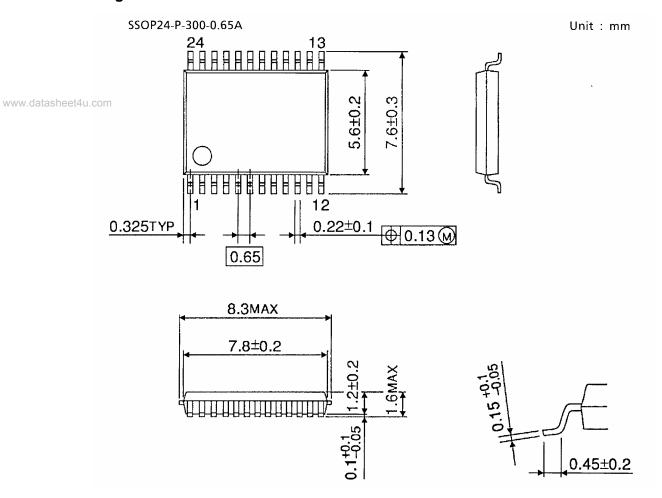








Package Dimensions



Weight: 0.14 g (typ.)

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About solderability, following conditions were confirmed

- Solderability
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 - · solder bath temperature = 230°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux
 - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - solder bath temperature = 245°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux